

# **TDA7479**

## SINGLE CHIP RDS DEMODULATOR + FILTER

- VERY HIGH RDS DEMODULATION QUALITY WITH IMPROVED DIGITAL SIGNAL PROCESSING
- HIGH PERFORMANCE, 57KHz BANDPASS FILTER (8th ORDER)
- FILTER ADJUSTMENT FREE AND WITHOUT EXTERNAL COMPONENTS
- PURELY DIGITAL RDS DEMODULATION WITHOUT EXTERNAL COMPONENTS
- ARI (SK INDICATION) AND RDS SIGNAL QUALITY OUTPUT
- 4.332MHz CRYSTAL OSCILLATOR(8.664 and 17.328MHz OPTIONAL)
- LOW NOISE CMOS TECHNOLOGY
- LOW RADIATION

#### **DESCRIPTION**

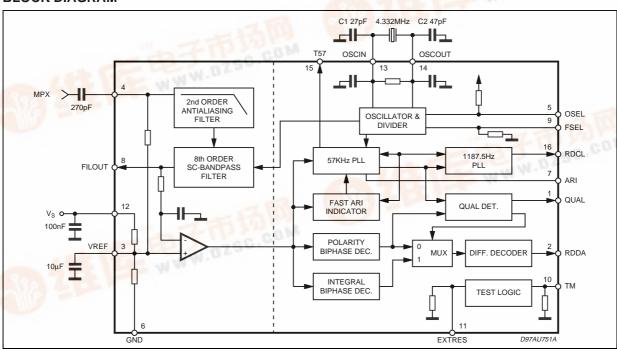
The TDA7479 recovers the additional inaudible RDS information which is transmitted by FM radio broadcasting stations and operates in accordance with the EBU (European Broadcasting Union) specifications.



The device is made up of two sections: a cascaded antialiasing + switched capacitors 8<sup>th</sup> bandpass filter for precise RDS band selection and a demodulating section that performs the extraction od RDS data stream (RDDA) and clock (RDCL), to be further processed by a suitable RDS decoder.

Outputs for RDS signal quality and ARI indication are also present.

#### **BLOCK DIAGRAM**

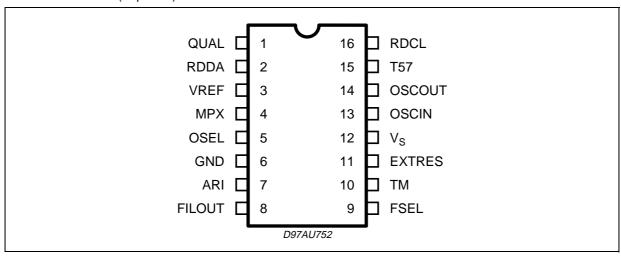




#### **PIN DESCRIPTION**

No pin	Name	Description
1	QUAL	Output for signal quality indication (High = good)
2	RDDA	RDS data output
3	VREF	Reference voltage
4	MPX	RDS input signal
5	OSEL	Oscillator selector pin: - open, closed to V <sub>S</sub> = quartz oscillator - closed to GND=external driven
6	GND	Ground
7	ARI	Output for ARI indication: - high when RDS+ARI are present - high when only ARI is present - low when only RDS is present - undefined when nos signal is present
8	FILOUT	Filter output
9	FSEL	Frequency selector pin: -100K to V <sub>S</sub> = 17.328MHz - open = 4.332MHz - closed to VS = 8.664MHz
10	TM	Test mode pin: - open = normal operation - closed to VS = testmode
11	EXTRES	Reset pin: - open=run mode - closed to VS = reset condition
12	Vs	Supply voltage
13	OSCIN	Oscillator input
14	OSCOUT	Oscillator output
15	T57	Testing output pin: 57kHz clock output
16	RDCL	RDS clock output 1187.5Hz

## PIN CONNECTION (Top view)



## THERMAL DATA

Ī	Symbol	Description	SO16	TSSOP16	Unit
Ī	R <sub>th j-case</sub>	Thermal Resistance Junction-case Max.	200	160	°C/W

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### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	-0.3 to 7	V
T <sub>op</sub>	Operating Temperature Range	-40 to 85	°C
T <sub>stg</sub>	Storage Temperature	-55 to 150	°C

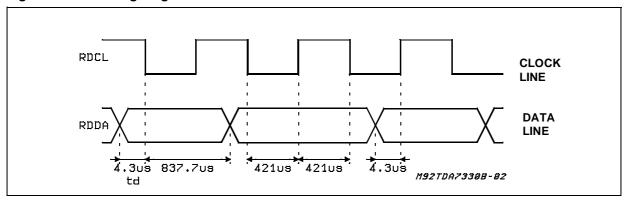
### **ELECTRICAL CHARACTERISTCS**

 $(T_{amb} = 25$ °C,  $V_S = 5$ V, unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply voltage		4.5	5	5.5	V
Is	Supply current			7.5	11.0	mA
FILTER			•			
f <sub>C</sub>	Center frequency		56.5	57	57.5	kHz
BW	3dB Bandwidth		2.5	3	3.5	kHz
G	Gain	f = 57kHz	18	20	22	dB
Α	Attenuation	$\Delta f \pm 4kHz$	18	22		dB
		f = 38kHz	50	60		dB
		f = 67kHz	35	45		dB
$R_{I}$	Input impedance of MPX		80	120	150	ΚΩ
$R_L$	Load impedance on FILOUT		1			MΩ
S/N	Signal to noise ratio	V <sub>IN</sub> = 3mVRMS	30	40		dB
V <sub>IN</sub>	MPX input signal	f = 19kHz; T3 ≤ 40dB(1) f = 57kHz (RDS+ ARI)			1000 50	mV <sub>RMS</sub>
$V_{REF}$	Reference			V <sub>S</sub> /2		V
DEMODU	LATOR		•			
Input pin Input pin	s (EXTRES, FSEL, TM) (OSEL)		all with ir with	nternal po n interna		
I <sub>PD</sub>	Input Current	V <sub>IN</sub> = 5V (pull-down input)	15		30	μΑ
I <sub>PU</sub>	Input Current	V <sub>IN</sub> = 0V (pull-up input)	-25		-10	μΑ
V <sub>IH</sub>	Input voltage high		0.7 · V <sub>S</sub>	0.8 · V <sub>S</sub>		V
VIL	Input voltage low			0.2 · V <sub>S</sub>	0.3 · V <sub>S</sub>	V
Output p	ins (RDCL, RDDA, ARI, QUAL, T	57)				
V <sub>OH</sub>	Ouput voltage high	I <sub>L</sub> = 0.5mA	4	4.6		V
$V_{OL}$	Output voltage low	I <sub>L</sub> = 0.5mA		0.4	1	V
OSCILLA	TOR	1	I			
VCLL	Input level OSCIN pin	OSEL = open circuit			1	V
VCLH	Input level OSCIN pin	OSEL = open circuit	4			V
	Amplitude OSCOUT	OSEL = open circuit		4.5		V
$V_{PP}$	Amplitude OSCIN (for external drive)	OSEL = GND, f = 4.332MHz OSEL = GND, f = 8.664MHz		100 120		mVpp mVpp
		OSEL = GND, f = 17.328MHz		150		mVpp

<sup>(1)</sup> The 3rd harmonic (57kHz) must be less than -40dB with respect to the input signal plus gain.

Figure 1. RDS timing diagram



#### **OUTPUT TIMING**

The RDS (1187.5Hz) output clock on RDCL line is synchronized to the incoming data. According to the internal PLL lock condition data change can result on the falling or on the rising clock edge. (see Fig. 1)Whichever clock edge is used by the decoder (rising or falling edge) the data will remain valid for 416.7  $\mu$ s after the clock transition.

### **OSCILLATOR CONTROLS (FSEL, OSEL)**

Three different crystal frequencies can be used. The adaption of the internal clock divider to the external crystal is achieved via the input pin FSEL. See the following table for reference:

Crystal	FSEL (pin configuration)
4.332MHz 8.664MHz 17.328MHz	connected to GND or openconnected to Vs external resistor of 100K to Vs

A special mode is introduced to reduce EMI. With pin OSEL connected to GND the internal oscillator is switched off and an external sinusoidal frequency could be applied on OSCIN. The peak to peak voltage of this signal can be reduced down to 60mV.

In this mode the frequency selection via FSEL is still active.

Suggested values of C1 and C2 are shown in the following table:

Crystal	C1	C2
4.332MHz	27pF	47pF
8.664MHz	27pF	-
17.328MHz	27pF	-

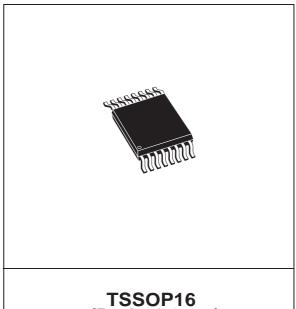
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DIM.		mm			inch	
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			1.200			0.047
A1	0.050		0.150	0.002		0.006
A2	0.800	1.000	1.050	0.031	0.039	0.041
b	0.190		0.300	0.007		0.012
С	0.090		0.200	0.005		0.009
D (1)	4.900	5.000	5.100	0.114	0.118	0.122
Е	6.200	6.400	6.600	0.244	0.252	0.260
E1 (1)	4.300	4.400	4.500	0.170	0.173	0.177
е		0.650			0.026	
L	0.450	0.600	0.750	0.018	0.024	0.030
L1		1.000			0.039	
k	0° (min.) 8° (max.)					
aaa			0.100			0.004

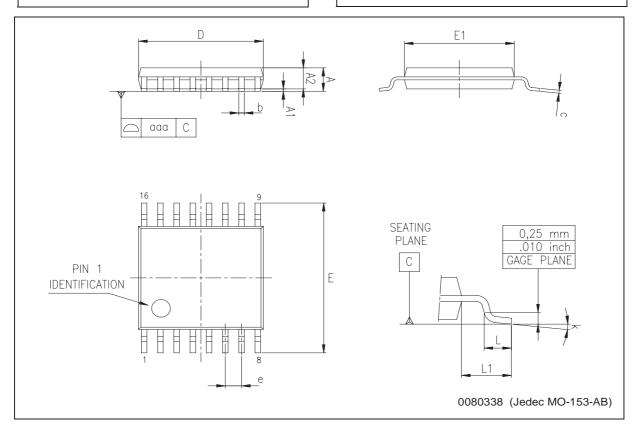
Note: 1. D and E1 does not include mold flash or protrusions.

Mold flash or potrusions shall not exceed 0.15mm
(.006inch) per side.

# OUTLINE AND MECHANICAL DATA

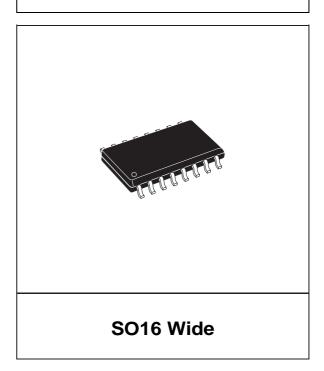


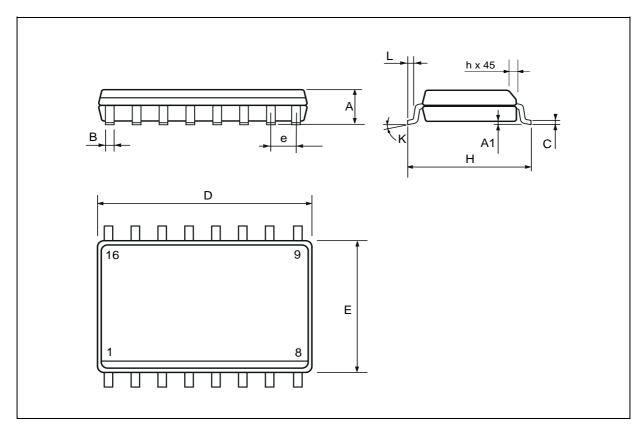
TSSOP16 (Body 4.4mm)



DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.35		2.65	0.093		0.104
A1	0.1		0.3	0.004		0.012
В	0.33		0.51	0.013		0.020
С	0.23		0.32	0.009		0.013
D	10.1		10.5	0.398		0.413
Е	7.4		7.6	0.291		0.299
е		1.27			0.050	
Н	10		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
L	0.4		1.27	0.016		0.050
К	0° (min.)8° (max.)					

# OUTLINE AND MECHANICAL DATA





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